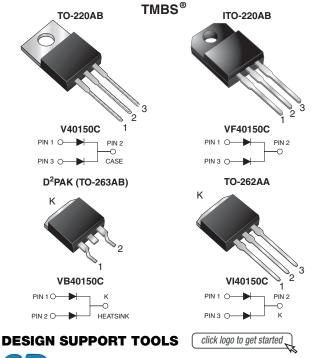
Vishay General Semiconductor

# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.55$  V at  $I_F = 5$  A



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PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub> 2 x 20 A						
V <sub>RRM</sub>	150 V					
I <sub>FSM</sub>	160 A					
$V_F$ at $I_F = 20$ A	0.75 V					
T <sub>J</sub> max.	150 °C					
Package	TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

#### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package) RoHS



- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

#### **MECHANICAL DATA**

**Case:** TO-220AB, ITO-220AB, D<sup>2</sup>PAK (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

#### Polarity: as marked

Mounting Torque: 10 in-lbs max.

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	V40150C	VF40150C	VB40150C	VI40150C	UNIT	
Max. repetitive peak reverse voltage		V <sub>RRM</sub>	150					
Max. average forward rectified current	per device	I <sub>F(AV)</sub>	40				A	
(fig. 1)	per diode	I <sub>F(AV)</sub>	20					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	160			А		
Non-repetitive avalanche energy at $T_J$ = 25 °C, L = 60 mH per diode		E <sub>AS</sub>	150			mJ		
Peak repetitive reverse current at $t_p$ = 2 µs, 1 kHz, $T_J$ = 38 °C ± 2 °C per diode		I <sub>RRM</sub>	0.5			А		
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000			V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V <sub>AC</sub>	1500			V		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150			°C		

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	ТҮР	MAX.	UNIT	
Breakdown voltage	I <sub>R</sub> = 1.0 mA	T <sub>A</sub> = 25 °C	V <sub>BR</sub>	150 (min.)	-	V	
Instantaneous forward voltage per diode <sup>(1)</sup>	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub>	0.69	-		
	I <sub>F</sub> = 10 A			0.84	-		
	I <sub>F</sub> = 20 A			1.15	1.43	v	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.55	-	v	
	I <sub>F</sub> = 10 A			0.64	-		
	I <sub>F</sub> = 20 A			0.75	0.82		
Reverse current per diode <sup>(2)</sup>	V <sub>R</sub> = 100 V	T <sub>A</sub> = 25 °C	I <sub>R</sub>	2	-	μA	
		T <sub>A</sub> = 125 °C		2.5	-	mA	
	V <sub>R</sub> = 150 V	T <sub>A</sub> = 25 °C		-	250	μA	
		T <sub>A</sub> = 125 °C		5	25	mA	

Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	SYMBOL	V40150C	VF40150C	VB40150C	VI40150C	UNIT	
Typical thermal resistance per diode	$R_{ ext{ heta}JC}$	1.8	4	1.8	1.8	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V40150C-E3/4W	1.89	4W	50/tube	Tube			
ITO-220AB	VF40150C-E3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VB40150C-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VB40150C-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VI40150C-E3/4W	1.46	4W	50/tube	Tube			

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

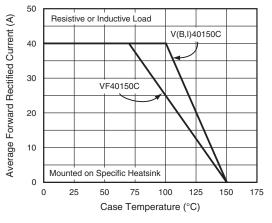


Fig. 1 - Maximum Forward Current Derating Curve

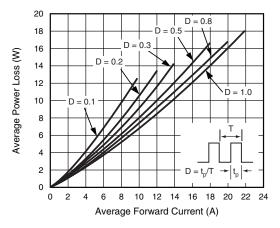
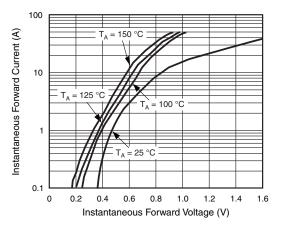


Fig. 2 - Forward Power Loss Characteristics Per Diode

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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

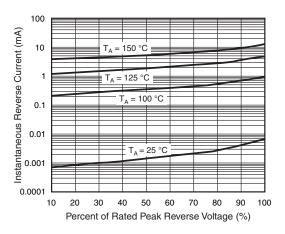


Fig. 4 - Typical Reverse Characteristics Per Diode

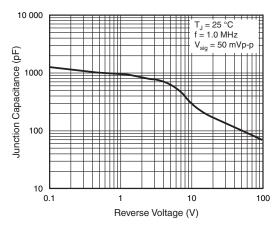


Fig. 5 - Typical Junction Capacitance

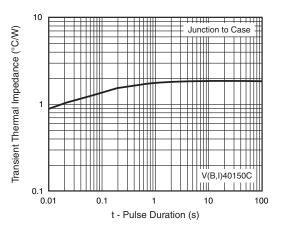


Fig. 6 - Typical Transient Thermal Impedance Per Diode

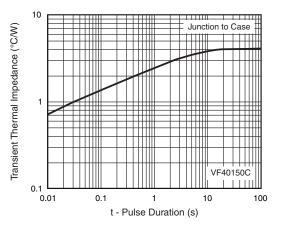


Fig. 7 - Typical Transient Thermal Impedance Per Diode

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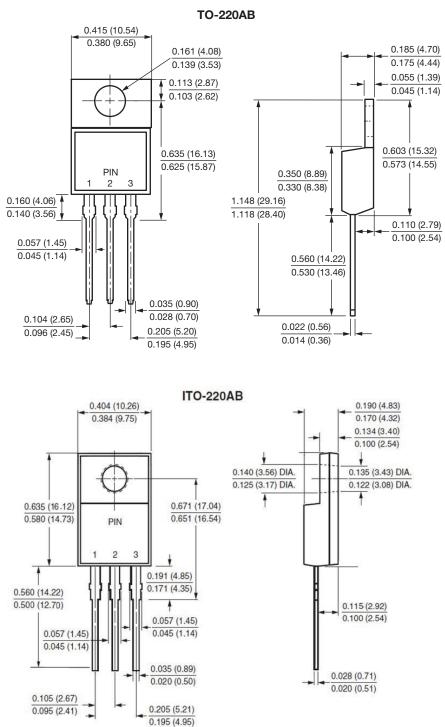
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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

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0.185 (4.70)

0.175 (4.44)

0.055 (1.40)

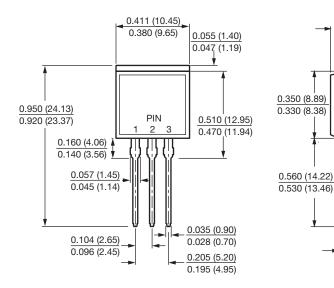
0.110 (2.79)

0.100 (2.54)

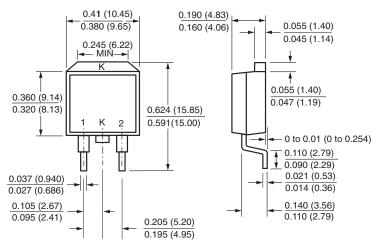
0.401 (10.19)

0.381 (9.68)

TO-262AA



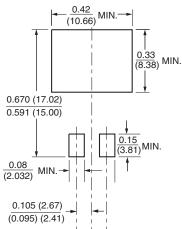
D<sup>2</sup>PAK (TO-263AB)



**Mounting Pad Layout** 

0.022 (0.56)

0.014 (0.35)



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